

**MOTOROLA
SEMICONDUCTOR**
TECHNICAL DATA

**1N5139 1N5139A
thru thru
1N5148 1N5148A**

SILICON EPICAP DIODES

... designed for electronic tuning and harmonic-generation applications, and providing solid-state reliability to replace mechanical tuning methods.

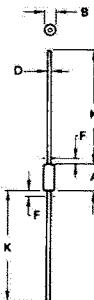
- Guaranteed High-Frequency Q
- Guaranteed Wide Tuning Range
- Guaranteed Temperature Coefficient
- Standard 10% Capacitance Tolerance
- Complete Typical Design Curves

**6.8-47 pF EPICAP
VOLTAGE-VARIABLE
CAPACITANCE DIODES**

**SILICON
EPITAXIAL PASSIVATED**

NOTES:

1. PACKAGE CONTOUR OPTIONAL WITHIN DIA B AND LENGTH A. HEAT SLUGS, IF ANY, SHALL BE INCLUDED WITHIN THIS CYLINDER, BUT SHALL NOT BE SUBJECT TO THE MIN LINE OF DIA B.
2. LEAD DIA NOT CONTROLLED IN ZONES F, TO ALLOW FOR FLASH, LEAD BURN BUILDUP, AND MINOR IRRREGULARITIES OTHER THAN HEAT SLUGS.



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	5.84	7.62	0.230	0.300
B	2.16	2.72	0.085	0.107
D	0.46	0.56	0.018	0.022
F	—	1.27	—	0.050
K	25.40	38.10	1.000	1.500

All JEDEC dimensions and notes apply

**CASE 51-02
DO-204AA**

1N5139 thru 1N5148, 1N5139A thru 1N5148A

ELECTRICAL CHARACTERISTICS (TA = 25°C unless otherwise noted)

Characteristic — All Types	Test Conditions	Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage	IR = 10 μ Adc	BVR	60	70	—	Vdc
Reverse Voltage Leakage Current	VR = 55 Vdc, TA = 25°C VR = 55 Vdc, TA = 150°C	IR	—	—	0.02 20	μ Adc
Series Inductance	f = 250 MHz, L = 1/16"	LS	—	5	—	nH
Case Capacitance	f = 1 MHz, L = 1/16"	CC	—	0.25	—	pF
Diode Capacitance Temperature Coefficient	VR = 4 Vdc, f = 1 MHz	TCC	—	200	300	ppm/ $^{\circ}$ C

Device	CT, Diode Capacitance VR = 4 Vdc, f = 1 MHz pF			Q, Figure of Merit VR = 4 Vdc, f = 50 MHz	α VR = 4 Vdc, f = 1 MHz		TR, Tuning Ratio C4/C60 f = 1 MHz	
	Min	Typ	Max		Min	Typ	Min	Typ
1N5139	6.1	6.8	7.5	350	0.37	0.40	2.7	2.9
1N5139A	6.5	6.8	7.1	350	0.37	0.40	2.7	2.9
1N5140	9.0	10.0	11.0	300	0.38	0.41	2.8	3.0
1N5140A	9.5	10.0	10.5	300	0.38	0.41	2.8	3.0
1N5141	10.8	12.0	13.2	300	0.38	0.41	2.8	3.0
1N5141A	11.4	12.0	12.6	300	0.38	0.41	2.8	3.0
1N5142	13.5	15.0	16.5	250	0.38	0.41	2.8	3.0
1N5142A	14.3	15.0	15.7	250	0.38	0.41	2.8	3.0
1N5143	16.2	18.0	19.8	250	0.38	0.41	2.8	3.0
1N5143A	17.1	18.0	18.9	250	0.38	0.41	2.8	3.0
1N5144	19.8	22.0	24.2	200	0.43	0.45	3.2	3.4
1N5144A	20.9	22.0	23.1	200	0.43	0.45	3.2	3.4
1N5145	24.3	27.0	29.7	200	0.43	0.45	3.2	3.4
1N5145A	25.7	27.0	28.3	200	0.43	0.45	3.2	3.4
1N5146	29.7	33.0	36.3	200	0.43	0.45	3.2	3.4
1N5146A	31.4	33.0	34.6	200	0.43	0.45	3.2	3.4
1N5147	36.1	39.0	42.9	200	0.43	0.45	3.2	3.4
1N5147A	37.1	39.0	40.9	200	0.43	0.45	3.2	3.4
1N5148	42.3	47.0	51.7	200	0.43	0.45	3.2	3.4
1N5148A	44.7	47.0	49.3	200	0.43	0.45	3.2	3.4

PARAMETER TEST METHODS

1. LS, SERIES INDUCTANCE

LS is measured on a shorted package at 250 MHz using an impedance bridge (Boonton Radio Model 250A RX Meter). L = lead length.

2. CC, CASE CAPACITANCE

CC is measured on an open package at 1 MHz using a capacitance bridge (Boonton Electronics Model 75A or equivalent).

3. Cr, DIODE CAPACITANCE

(Cr = Cc + Cg). Cr is measured at 1 MHz using a capacitance bridge (Boonton Electronics Model 75A or equivalent).

4. TR, TUNING RATIO

TR is the ratio of Cr measured at 4 Vdc divided by Cr measured at 60 Vdc.

5. Q, FIGURE OF MERIT

Q is calculated by taking the G and C readings of an admittance bridge at the specified frequency and substituting in the following equations:

$$Q = \frac{2\pi f C}{G}$$

(Boonton Electronics Model 33ASB).

6. α , DIODE CAPACITANCE REVERSE VOLTAGE SLOPE

The diode capacitance, Cr (as measured at Vd = 4 Vdc, f = 1 MHz) is compared to Cr (as measured at Vd = 60 Vdc, f = 1 MHz) by the following equation which defines α .

$$\alpha = \frac{\log C_r(4) - \log C_r(60)}{\log 60 - \log 4}$$

Note that a Cr versus Vd law is assumed as shown in the following equation where Cc is included.

$$C_r = \frac{K}{V^{\alpha}}$$

7. TCC, DIODE CAPACITANCE TEMPERATURE COEFFICIENT

TCC is guaranteed by comparing Cr at Vd = 4 Vdc, f = 1 MHz, TA = -65°C with Cr at Vd = 4 Vdc, f = 1 MHz, TA = +85°C in the following equation which defines TCC:

$$TCC = \left| \frac{C_r(+85^{\circ}C) - C_r(-65^{\circ}C)}{85 + 65} \right| \cdot \frac{10^4}{C_r(25^{\circ}C)}$$

1N5139 thru 1N5148, 1N5139A thru 1N5148A

